

**10-PZ126PA075ME-M909F38Y**

datasheet

Vincotech

flowPACK 0 SiC	1200 V / 75 mΩ
Topology features <ul style="list-style-type: none">• 3xHalf Bridge• Open Emitter configuration• Kelvin Emitter for improved switching performance• Integrated DC capacitor• Split output for transient deactivation of the body diode and elimination of X-conduction at fast turn-on• Temperature sensor	flow 0 12 mm housing
Component features <ul style="list-style-type: none">• High Blocking Voltage with low drain source on state resistance• High speed SiC-MOSFET technology• Resistant to Latch-up	
Housing features <ul style="list-style-type: none">• Base isolation: Al₂O₃• Clip-in, reliable mechanical connection, qualified for wave soldering• Convex shaped substrate for superior thermal contact• Thermo-mechanical push-and-pull force relief• Press-fit pin• Reliable cold welding connection	Schematic <pre>graph LR; subgraph Top [Top]; D1[Diode] --- S1[Source]; end; subgraph Middle [Middle]; D2[Diode] --- S2[Source]; end; subgraph Bottom [Bottom]; D3[Diode] --- S3[Source]; end; D1 --- GND; S1 --- D1; S2 --- D2; S3 --- D3; D1 --- D2 --- D3;</pre>
Target applications <ul style="list-style-type: none">• Power Supply• Solar Inverters	
Types <ul style="list-style-type: none">• 10-PZ126PA075ME-M909F38Y	



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Drain-source voltage	V_{DSS}		1200	V
Drain current (DC current)	I_D	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	21	A
Peak drain current	I_{DM}	t_p limited by T_{jmax}	80	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	52	W
Gate-source voltage	V_{GSS}		-4 / 15	V
		dynamic	-8 / 19	
Maximum Junction Temperature	T_{jmax}		175	°C

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	14	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	47	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$ $T_j = 25^\circ\text{C}$	71	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	40	W
Maximum junction temperature	T_{jmax}		175	°C

Capacitor (DC)

Maximum DC voltage	V_{MAX}		1000	V
Operation Temperature	T_{op}		0 ... 125	°C



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
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Module Properties

Thermal Properties				
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Storage temperature	T_{stg}		-40...+125	°C
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
Isolation voltage	V_{isol}	AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				>12,7	mm
Clearance				10,19	mm
Comparative Tracking Index	CTI			≥ 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Drain-source on-state resistance	$r_{DS(on)}$		15		20	25 125 150		81,5 105 117	90 ⁽¹⁾	mΩ
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$	0		0,005	25	1,7	2,5	4	V
Gate to Source Leakage Current	I_{GSS}		15	0		25		10	250	nA
Zero Gate Voltage Drain Current	I_{DSS}		0	1200		25		1	100	μA
Internal gate resistance	r_g							10,5		Ω
Gate charge	Q_g		-4/15	800	20	25		54		nC
Short-circuit input capacitance	C_{iss}	$f = 1 \text{ MHz}$	0	1000	0	25		1350		pF
Short-circuit output capacitance	C_{oss}							58		
Reverse transfer capacitance	C_{rss}							3		
Diode forward voltage	V_{SD}		0		10	25		4,5		V

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						1,84		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 21,33 \Omega$ $R_{goff} = 21,33 \Omega$	$-4/15$	600	15	25 125 150		25,21 22,17 22,04		ns
Rise time	t_r					25 125 150		18,34 17,46 17,1		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		94 103,71 106,36		ns
Fall time	t_f	$Q_{fFWD}=0,123 \mu\text{C}$ $Q_{fFWD}=0,136 \mu\text{C}$ $Q_{fFWD}=0,139 \mu\text{C}$				25 125 150		28,56 27,98 28,73		ns
Turn-on energy (per pulse)	E_{on}					25 125 150		0,278 0,261 0,258		mWs
Turn-off energy (per pulse)	E_{off}					25 125 150		0,099 0,101 0,103		mWs



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Inverter Diode

Static

Forward voltage	V_F				10	25 125 150		1,51 2,02 2,13	1,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 1200$ V				25		30	250	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						2,39		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=976$ A/µs $di/dt=1120$ A/µs $di/dt=1090$ A/µs	-4/15	600	15	25 125 150		6,52 7,25 7,46		A
Reverse recovery time	t_{rr}					25 125 150		31,22 31,34 30,87		ns
Recovered charge	Q_r					25 125 150		0,123 0,136 0,139		µC
Reverse recovered energy	E_{rec}		-4/15	600	15	25 125 150		0,027 0,033 0,034		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		871,86 625,05 649,49		A/µs



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Capacitor (DC)

Static

Capacitance	C	DC bias voltage = 0 V				25		47		nF
Tolerance						-10		10		%

Thermistor

Static

Rated resistance	R					25		5		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 499 \Omega$				100	3,2		3,3	%
Power dissipation	P				25		130			mW
Power dissipation constant	d				25		1,3			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3380		K
Vincotech Thermistor Reference									V	

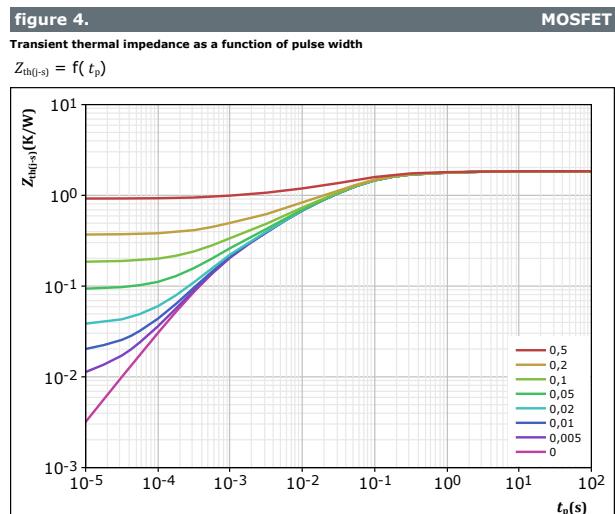
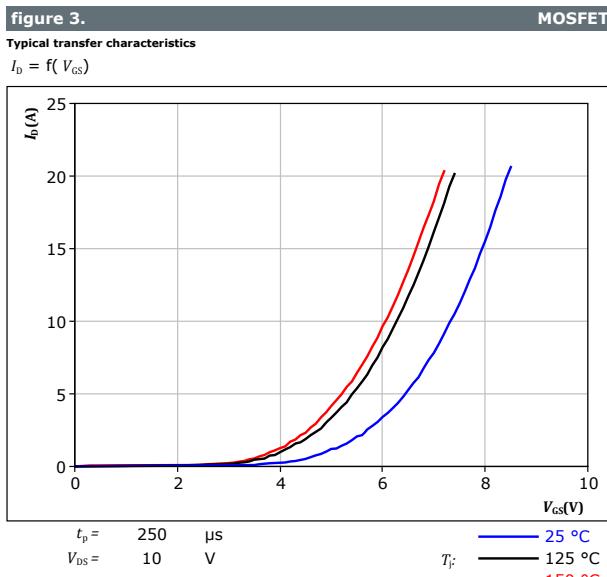
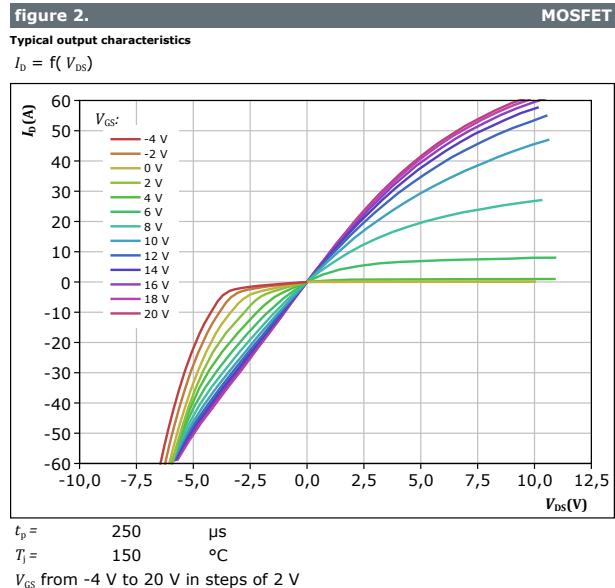
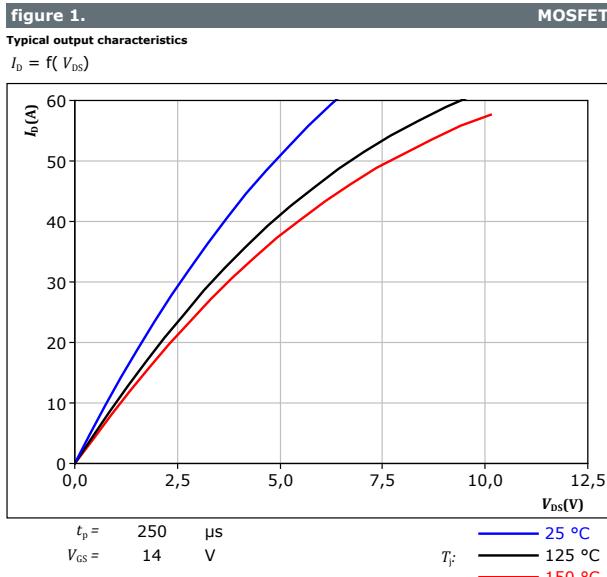
⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



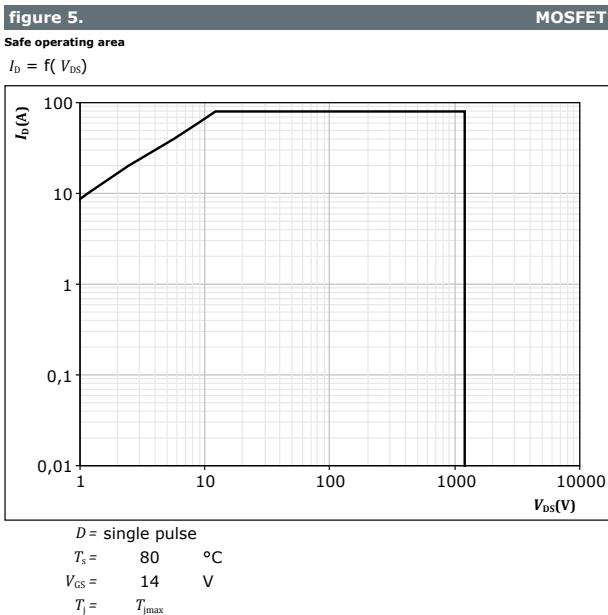
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Inverter Switch Characteristics





Inverter Switch Characteristics





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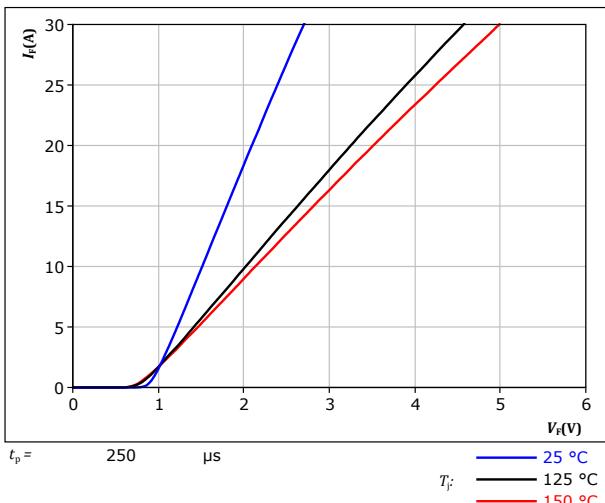
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Inverter Diode Characteristics

figure 6.

Typical forward characteristics

$$I_F = f(V_F)$$

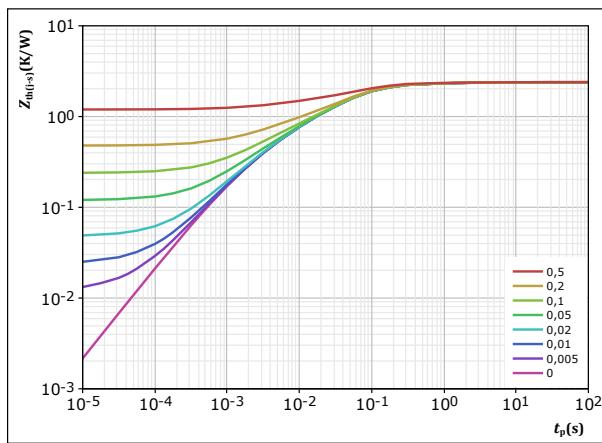


FWD

figure 7.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

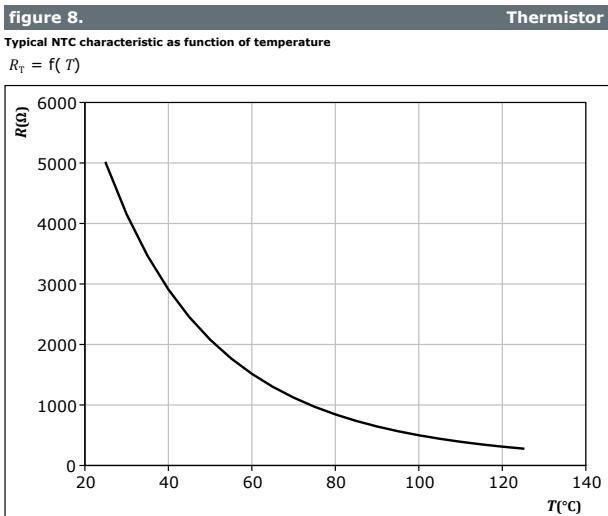
$$D = \frac{t_p / T}{2,392} \quad K/W$$

FWD thermal model values

R (K/W)	τ (s)
7,48E-02	2,91E+00
2,03E-01	3,58E-01
1,24E+00	6,46E-02
4,88E-01	1,70E-02
3,16E-01	3,69E-03
7,23E-02	8,74E-04



Thermistor Characteristics



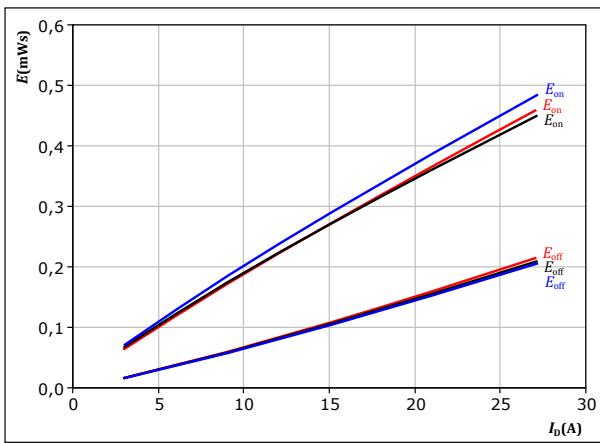


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Inverter Switching Characteristics

figure 9.

Typical switching energy losses as a function of drain current
 $E = f(I_D)$



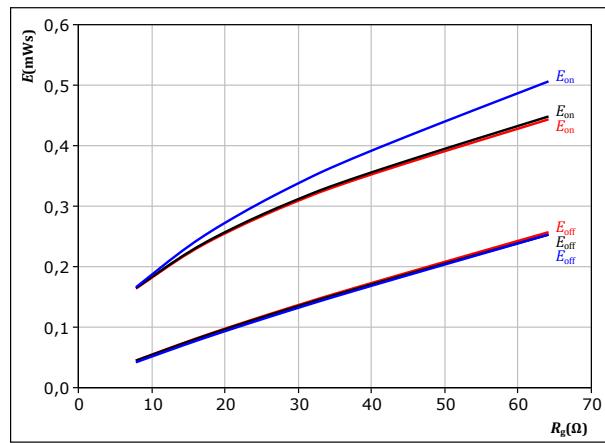
With an inductive load at

$V_{DS} = 600$ V $T_f:$ 25 °C
 $V_{GS} = -4/15$ V 125 °C
 $R_{gon} = 21,33$ Ω 150 °C
 $R_{goff} = 21,33$ Ω

MOSFET

figure 10.

Typical switching energy losses as a function of MOSFET turn on gate resistor
 $E = f(R_g)$



With an inductive load at

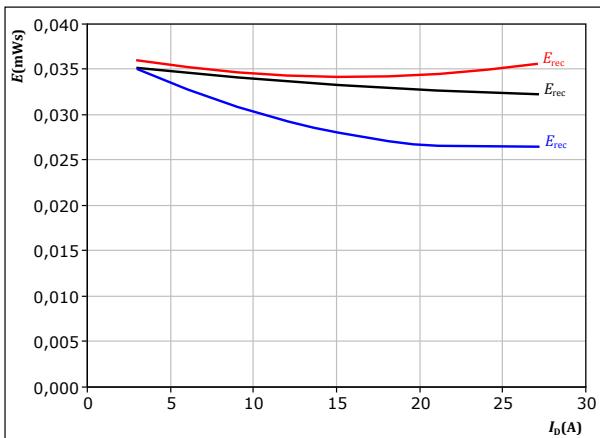
$V_{DS} = 600$ V $T_f:$ 25 °C
 $V_{GS} = -4/15$ V 125 °C
 $I_D = 15$ A 150 °C

MOSFET

figure 11.

Typical reverse recovered energy loss as a function of drain current

$E_{rec} = f(I_D)$



With an inductive load at

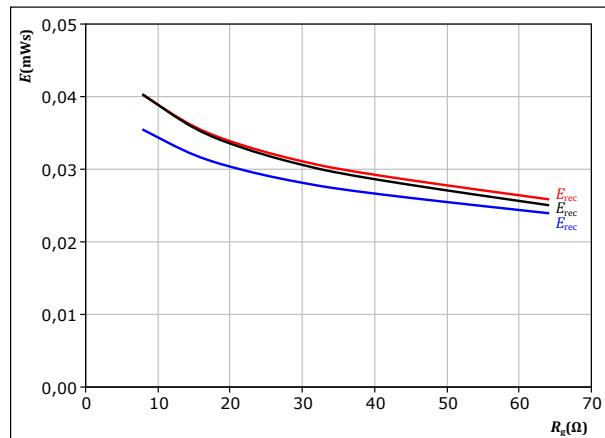
$V_{DS} = 600$ V $T_f:$ 25 °C
 $V_{GS} = -4/15$ V 125 °C
 $R_{gon} = 21,33$ Ω 150 °C

FWD

figure 12.

Typical reverse recovered energy loss as a function of MOSFET turn on gate resistor

$E_{rec} = f(R_g)$



With an inductive load at

$V_{DS} = 600$ V $T_f:$ 25 °C
 $V_{GS} = -4/15$ V 125 °C
 $I_D = 15$ A 150 °C

FWD

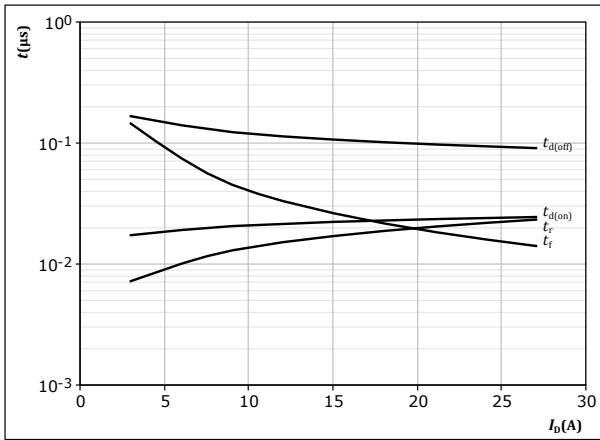


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Inverter Switching Characteristics

figure 13.

Typical switching times as a function of drain current
 $t = f(I_D)$



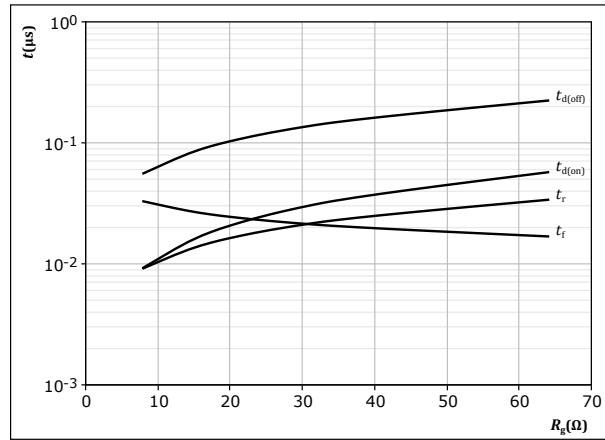
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $R_{gon} = 21,33 \Omega$
 $R_{goff} = 21,33 \Omega$

MOSFET

figure 14.

Typical switching times as a function of MOSFET turn on gate resistor
 $t = f(R_g)$



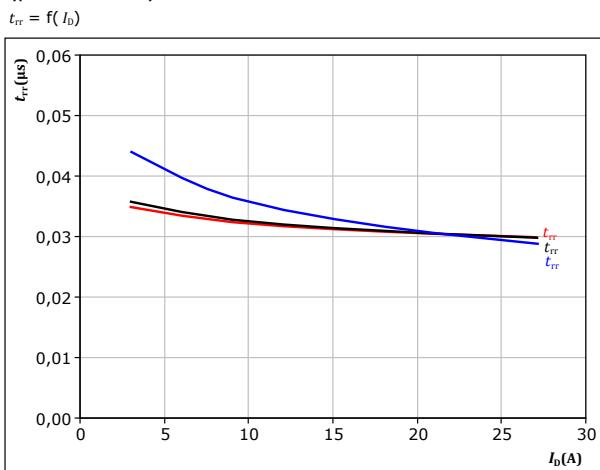
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $I_D = 15 \text{ A}$

MOSFET

figure 15.

Typical reverse recovery time as a function of drain current
 $t_{rr} = f(I_D)$

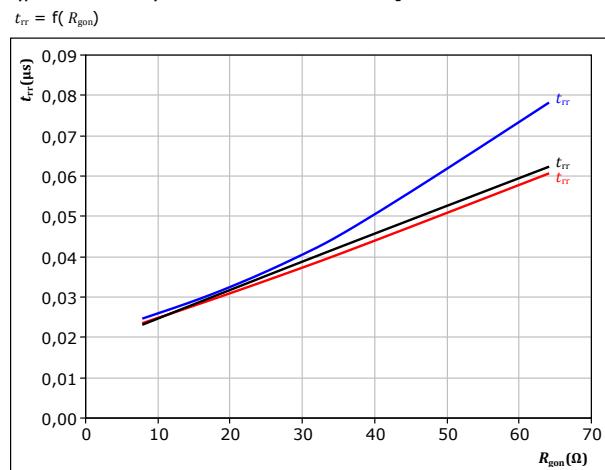


At $V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $R_{gon} = 21,33 \Omega$

FWD

figure 16.

Typical reverse recovery time as a function of MOSFET turn on gate resistor
 $t_{rr} = f(R_{gon})$



At $V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $I_D = 15 \text{ A}$

FWD

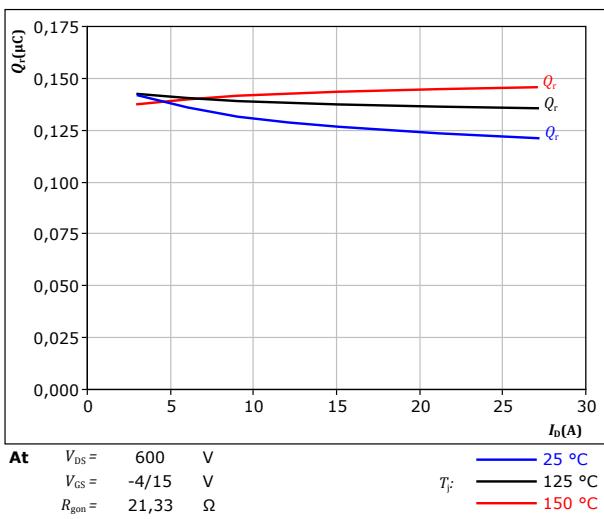


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Inverter Switching Characteristics

figure 17.

Typical recovered charge as a function of drain current
 $Q_r = f(I_D)$

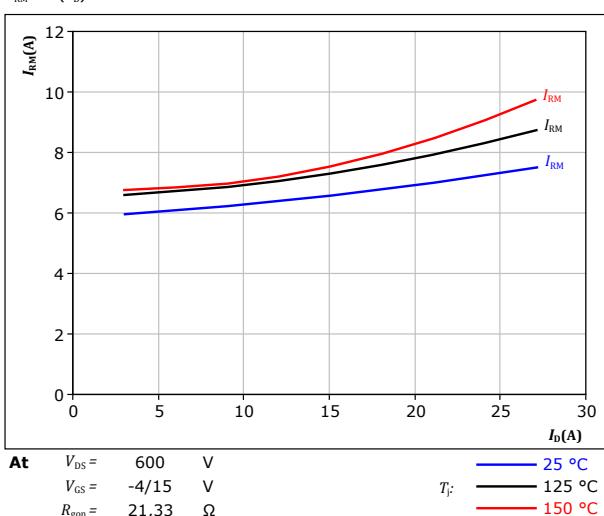


FWD

FWD

figure 19.

Typical peak reverse recovery current as a function of drain current
 $I_{RM} = f(I_D)$

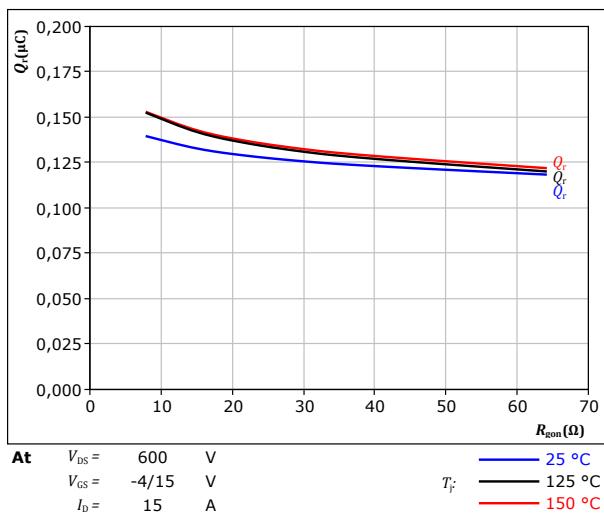


FWD

FWD

figure 18.

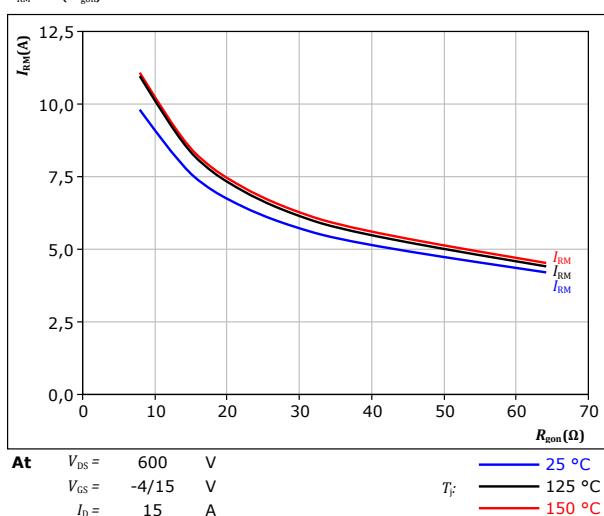
Typical recovered charge as a function of MOSFET turn on gate resistor
 $Q_r = f(R_{gon})$



FWD

figure 20.

Typical peak reverse recovery current as a function of MOSFET turn on gate resistor
 $I_{RM} = f(R_{gon})$



FWD



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Inverter Switching Characteristics

figure 21. FWD

Typical rate of fall of forward and reverse recovery current as a function of drain current
 $di_f/dt, di_{rr}/dt = f(I_D)$

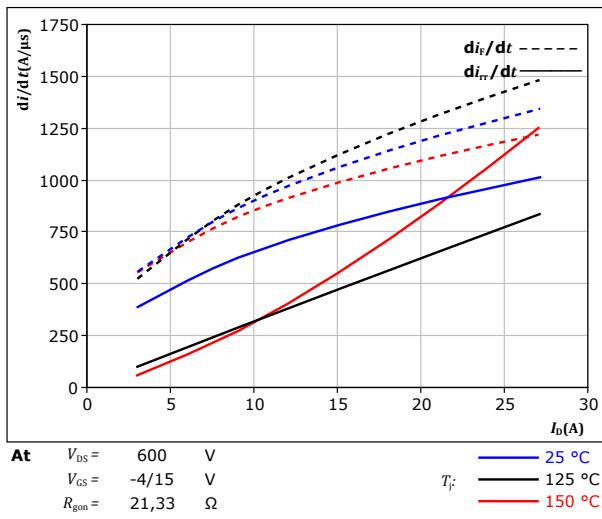


figure 22. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$

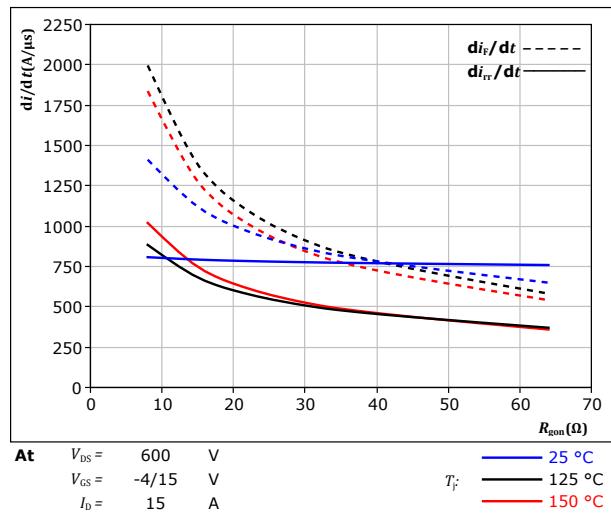
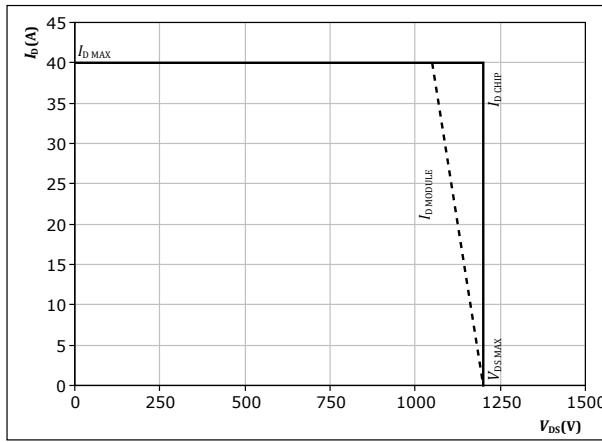


figure 23. MOSFET

Reverse bias safe operating area

$I_D = f(V_{DS})$





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Inverter Switching Definitions

figure 24. MOSFET

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

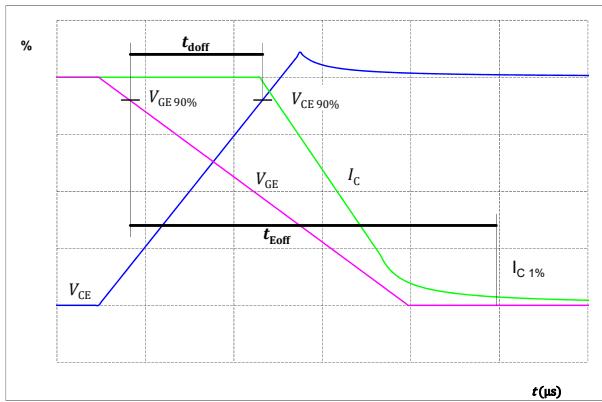


figure 25. MOSFET

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

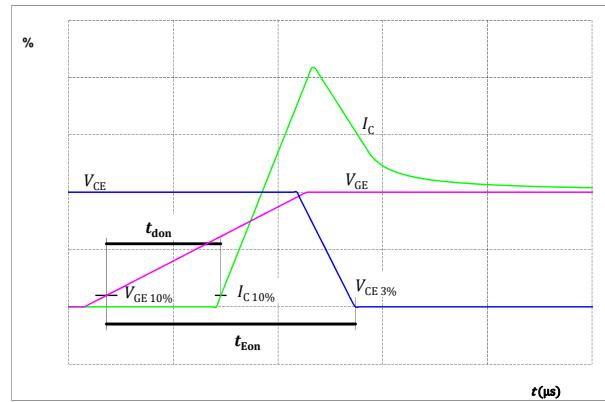


figure 26. MOSFET

Turn-off Switching Waveforms & definition of t_f

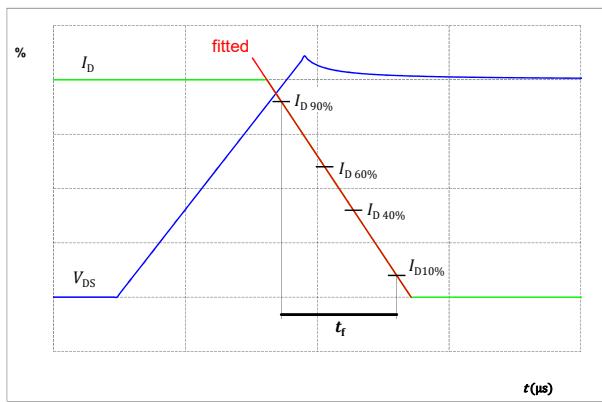
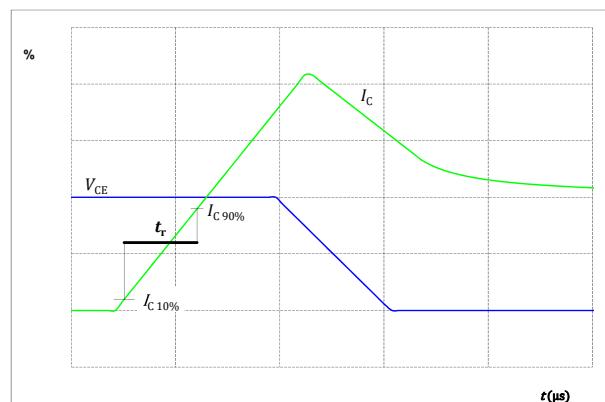


figure 27. MOSFET

Turn-on Switching Waveforms & definition of t_r





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Inverter Switching Definitions

figure 28.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

Turn-off Switching Waveforms & definition of t_{tr}

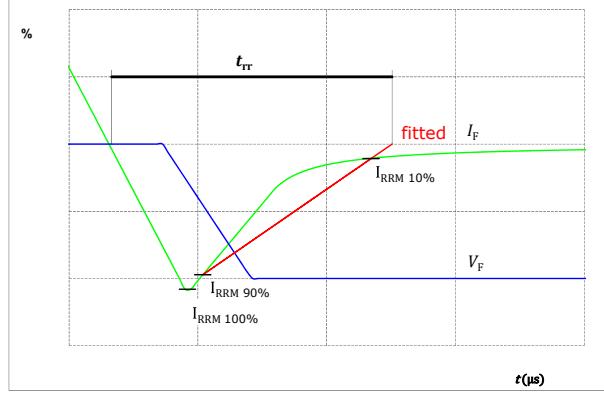


figure 29.

Turn-on Switching Waveforms & definition of t_{Qtr} (t_{Qtr} = integrating time for Q_{tr})

FWD

Turn-on Switching Waveforms & definition of t_{Qtr} (t_{Qtr} = integrating time for Q_{tr})

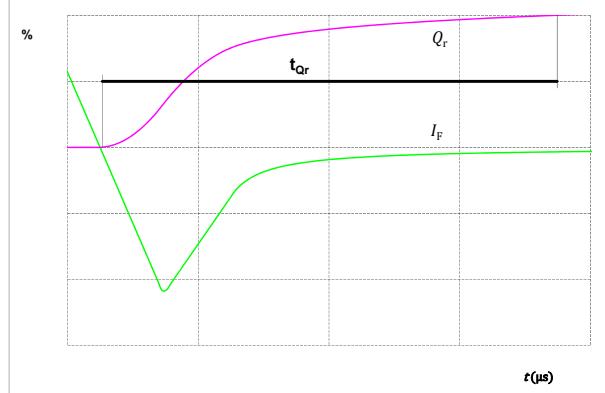
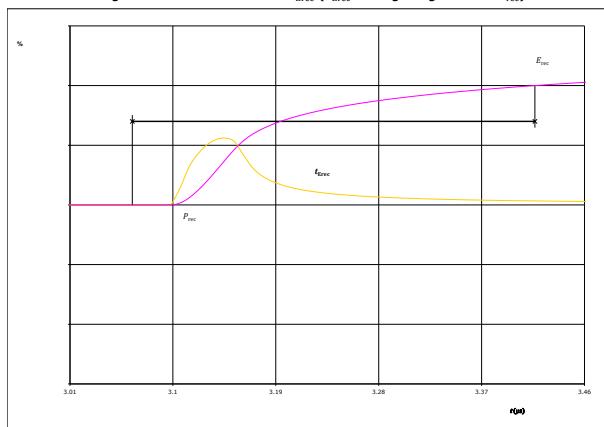


figure 30.

Turn-on Switching Waveforms & definition of t_{Erec} (t_{Erec} = integrating time for E_{rec})

FWD

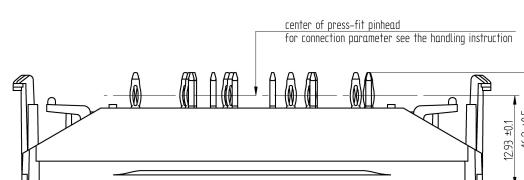
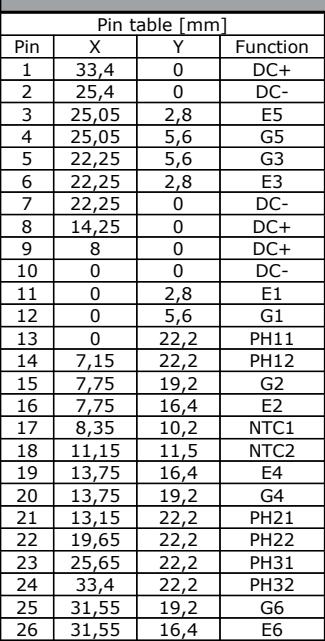
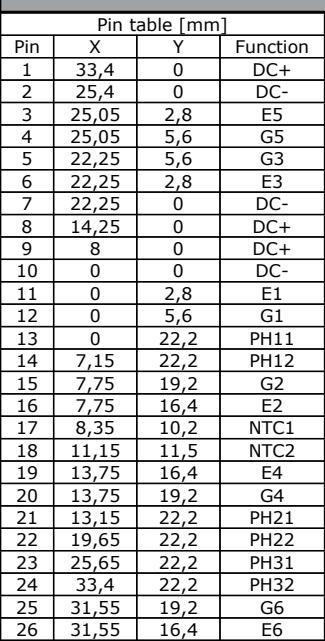
Turn-on Switching Waveforms & definition of t_{Erec} (t_{Erec} = integrating time for E_{rec})



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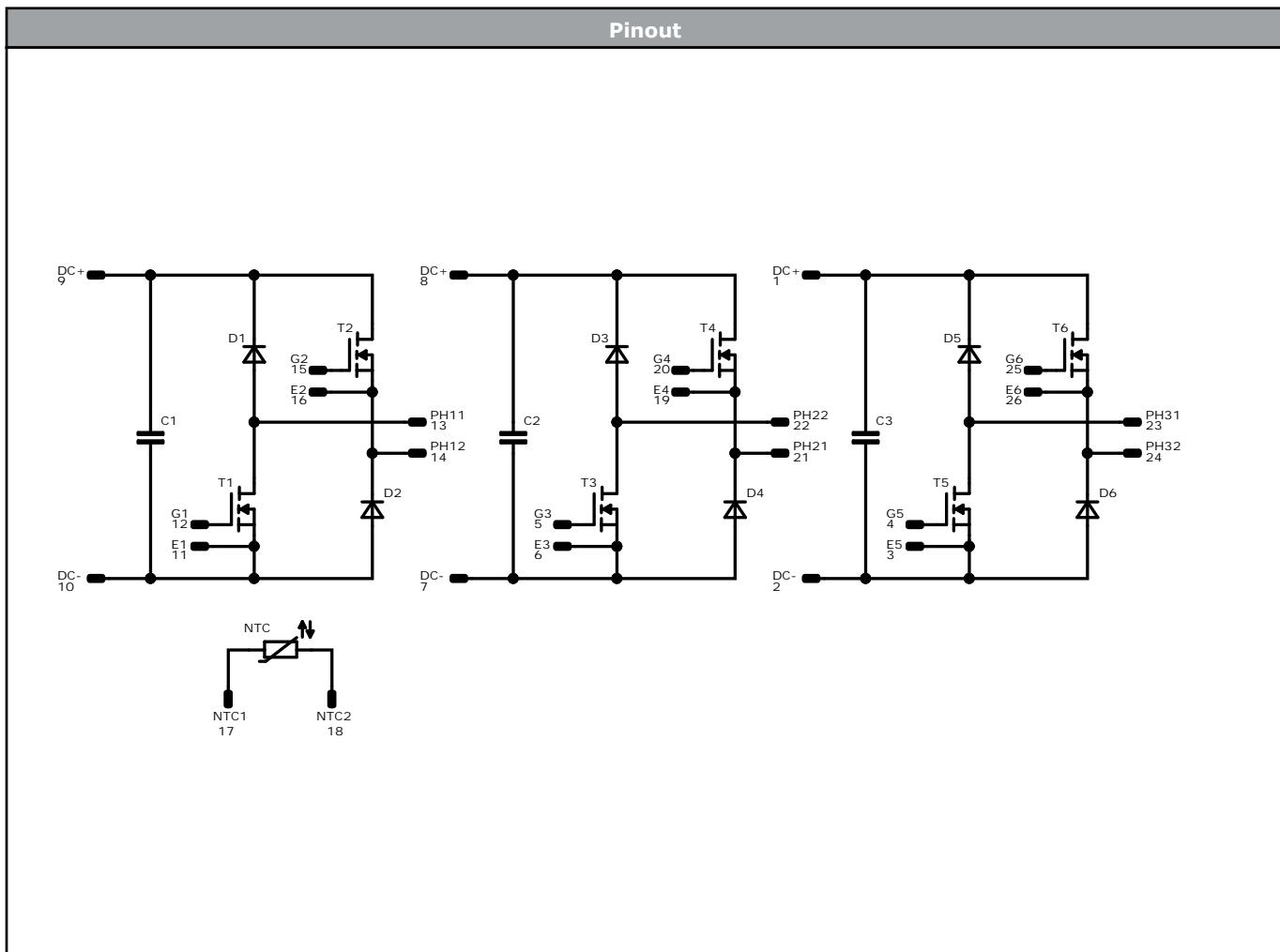
datasheet

Vincotech

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With thermal paste (3,4 W/mK, PSX-P7)				10-PZ126PA075ME-M909F38Y-/3/																																																																																																															
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	Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY																																																																																																														
Outline																																																																																																																			
Pin table [mm]	 <p>center of press-fit pinhead For connection parameter see the handling instruction</p>  <table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>33,4</td><td>0</td><td>DC+</td></tr><tr><td>2</td><td>25,4</td><td>0</td><td>DC-</td></tr><tr><td>3</td><td>25,05</td><td>2,8</td><td>E5</td></tr><tr><td>4</td><td>25,05</td><td>5,6</td><td>G5</td></tr><tr><td>5</td><td>22,25</td><td>5,6</td><td>G3</td></tr><tr><td>6</td><td>22,25</td><td>2,8</td><td>E3</td></tr><tr><td>7</td><td>22,25</td><td>0</td><td>DC-</td></tr><tr><td>8</td><td>14,25</td><td>0</td><td>DC+</td></tr><tr><td>9</td><td>8</td><td>0</td><td>DC+</td></tr><tr><td>10</td><td>0</td><td>0</td><td>DC-</td></tr><tr><td>11</td><td>0</td><td>2,8</td><td>E1</td></tr><tr><td>12</td><td>0</td><td>5,6</td><td>G1</td></tr><tr><td>13</td><td>0</td><td>22,2</td><td>PH11</td></tr><tr><td>14</td><td>7,15</td><td>22,2</td><td>PH12</td></tr><tr><td>15</td><td>7,75</td><td>19,2</td><td>G2</td></tr><tr><td>16</td><td>7,75</td><td>16,4</td><td>E2</td></tr><tr><td>17</td><td>8,35</td><td>10,2</td><td>NTC1</td></tr><tr><td>18</td><td>11,15</td><td>11,5</td><td>NTC2</td></tr><tr><td>19</td><td>13,75</td><td>16,4</td><td>E4</td></tr><tr><td>20</td><td>13,75</td><td>19,2</td><td>G4</td></tr><tr><td>21</td><td>13,15</td><td>22,2</td><td>PH21</td></tr><tr><td>22</td><td>19,65</td><td>22,2</td><td>PH22</td></tr><tr><td>23</td><td>25,65</td><td>22,2</td><td>PH31</td></tr><tr><td>24</td><td>33,4</td><td>22,2</td><td>PH32</td></tr><tr><td>25</td><td>31,55</td><td>19,2</td><td>G6</td></tr><tr><td>26</td><td>31,55</td><td>16,4</td><td>E6</td></tr></tbody></table>	Pin	X	Y	Function	1	33,4	0	DC+	2	25,4	0	DC-	3	25,05	2,8	E5	4	25,05	5,6	G5	5	22,25	5,6	G3	6	22,25	2,8	E3	7	22,25	0	DC-	8	14,25	0	DC+	9	8	0	DC+	10	0	0	DC-	11	0	2,8	E1	12	0	5,6	G1	13	0	22,2	PH11	14	7,15	22,2	PH12	15	7,75	19,2	G2	16	7,75	16,4	E2	17	8,35	10,2	NTC1	18	11,15	11,5	NTC2	19	13,75	16,4	E4	20	13,75	19,2	G4	21	13,15	22,2	PH21	22	19,65	22,2	PH22	23	25,65	22,2	PH31	24	33,4	22,2	PH32	25	31,55	19,2	G6	26	31,55	16,4	E6	 <p>Tolerance of pinpositions $\pm 0.5\text{mm}$ at the end of pins Dimension of coordinate axis is only offset without tolerance</p>					
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Vincotech



Identification

ID	Component	Voltage	Current	Function	Comment
T1, T2, T3, T4, T5, T6	MOSFET	1200 V	75 mΩ	Inverter Switch	
D1, D2, D3, D4, D5, D6	FWD	1200 V	10 A	Inverter Diode	
C1, C2, C3	Capacitor	1000 V		Capacitor (DC)	
NTC	Thermistor			Thermistor	



10-PZ126PA075ME-M909F38Y

datasheet

Vincotech

Packaging instruction				
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ	Sample

Handling instruction				
Handling instructions for flow 0 packages see vincotech.com website.				

Package data				
Package data for flow 0 packages see vincotech.com website.				

Vincotech thermistor reference				
See Vincotech thermistor reference table at vincotech.com website.				

UL recognition and file number				
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.				

Document No.:	Date:	Modification:	Pages
10-PZ126PA075ME-M909F38Y-D1-14	31 Aug. 2022		

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